INTEGRATED CIRCUITS

DATA SHEET

NE522

High-speed dual-differential comparator/sense amp

Product data Supersedes data of 1994 Aug 31 File under Integrated Circuits, IC11 Handbook





High-speed dual-differential comparator/sense amp

NE522

FEATURES

- 15 ns maximum guaranteed propagation delay
- 20 µA maximum input bias current
- TTL-compatible strobes and outputs
- Large common-mode input voltage range
- Operates from standard supply voltages

APPLICATIONS

- MOS memory sense amp
- A-to-D conversion
- High-speed line receiver

PIN CONFIGURATION

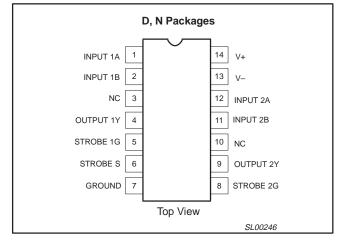


Figure 1. Pin Configuration

BLOCK DIAGRAM

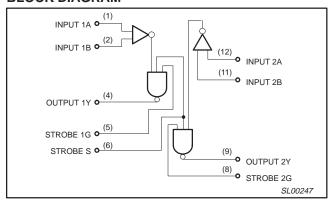


Figure 2. Block Diagram

ORDERING INFORMATION

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE	DWG#
14-Pin Plastic DIP	0 °C to +70 °C	NE522N	SOT27-1
14-Pin Plastic SO	0 °C to +70 °C	NE522D	SOT108-1

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNITS
V+ V-	Single supply voltage Positive Negative	+7 -7	V V
V _{IDR}	Differential input voltage	±6	V
V _{IN}	Input voltage Common-mode Strobe/gate	±5 +5.25	V V
P _D	Power dissipation	600	mW
T _{amb}	Operating temperature range	0 to 70	°C
T _{stg}	Storage temperature range	-65 to +150	°C
T _{sld}	Lead soldering temperature (10 sec max)	+230	°C

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EQUIVALENT SCHEMATIC

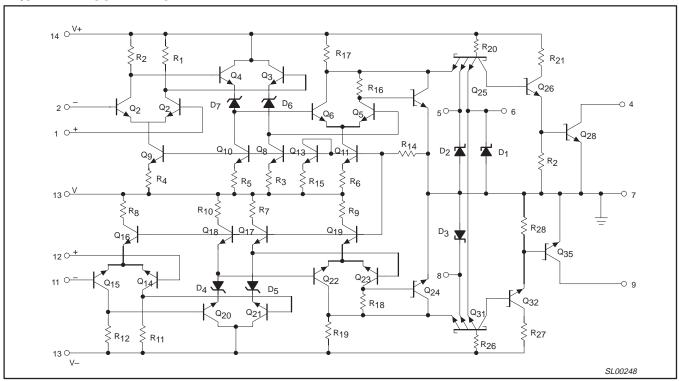


Figure 3. Equivalent Schematic

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DC ELECTRICAL CHARACTERISTICS

V± = ±5 V ±5%; T_{amb} = 0 °C to +70 °C, unless otherwise stated.

SYMBOL	DADAMETED	TEST CONDITIONS		LIMITS		UNITS
SYMBOL	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIIS
V _{OS}	Input offset voltage At 25 °C Over temperature range	V+ = +4.75 V; V- = -4.75 V		6	7.5 10	mV mV
I _{BIAS}	Input bias current At 25 °C Over temperature range	V+ = +5.25 V; V- = -5.25 V		7.5	20 40	μΑ μΑ
I _{OS}	Input offset current At 25 °C Over temperature range	V+ = +5.25 V; V- = -5.25 V		1.0	5 12	μΑ μΑ
V_{CM}	Common-mode voltage range	V+ = +4.75 V; V- = -4.75 V	-3		+3	V
V _{IL}	LOW-level input voltage At 25 °C Over temperature range				0.8 0.7	V V
V _{IH}	High level temperature		2.0			V
Іін	HIGH-level input current 1G or 2G strobe Common strobe S	V+ = +5.25 V; V- = -5.25 V; V _{IH} = 2.7 V			50 100	μΑ μΑ
I _{IL}	LOW-level input current 1G or 2G strobe Common strobe S	V _{IL} = 0.5 V			-2.0 -4.0	mA mA
V _{OL}	LOW-level output voltage	$V+ = +5.25 \text{ V}; V- = -5.25 \text{ V}; V_{I(S)} = 2.0 \text{ V};$ $I_{LOAD} = 20 \text{ mA}$			0.5	V
I _{OH}	HIGH-level output current	V+ = +4.75 V; V- = -4.75 V; V _{OH} = 5.25 V			250	μΑ
V+ V-	Supply voltage Positive Negative		4.75 -4.75	5.0 -5.0	5.25 -5.25	V V
I _{CC+}	Supply current Positive Negative	V+ = +5.25 V; V- = -5.25 V; T _{amb} = 25 °C		27 –15	35 –28	mA

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AC ELECTRICAL CHARACTERISTICS

 $\rm T_{amb}$ = 25 °C; R_L = 280 Ω ; C_L = 15 pF; unless otherwise stated.

CVMDOL	DADAMETED	EDOM INDUT	TO OUTDUT		LIMITO		
SYMBOL	PARAMETER	FROM INPUT	TO OUTPUT	MIN	TYP	MAX	UNITS
I _R	Input resistance				4		kΩ
I _C	Input capacitance				3		pF
Large-sig	nal switching speed						
	Propagation delay						
t _{PLH(D)}	Low to high ¹	Amp	Output		10	15	
t _{PHL(D)}	High to low ¹	Amp	Output		8	12	ns
t _{PLH(S)}	Low to high ²	Strobe	Output		6	13	
t _{PHL(S)}	High to low ²	Strobe	Output		5	9	
I _{MAX}	Maximum operating frequency			25	35		MHz

NOTES:

Response time measured from 0 V point of +100 mV_{P-P} 10 MHz square wave to the 1.5 V point of the output.
 Response time measured from 1.5 V point of the input to 1.5 V point of the output.

LOGIC FUNCTION TABLE

V _{ID} (A+, B-)	STRS	STRG	OUTPUT TRANSISTOR
<-V _{OS}	Н	Н	ON
$-V_{OS} < V_{ID} < V_{OS}$	Н	Н	Undefined
> V _{OS}	Н	Н	OFF
X	L	Х	OFF
X	Х	L	OFF

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TYPICAL PERFORMANCE CHARACTERISTICS

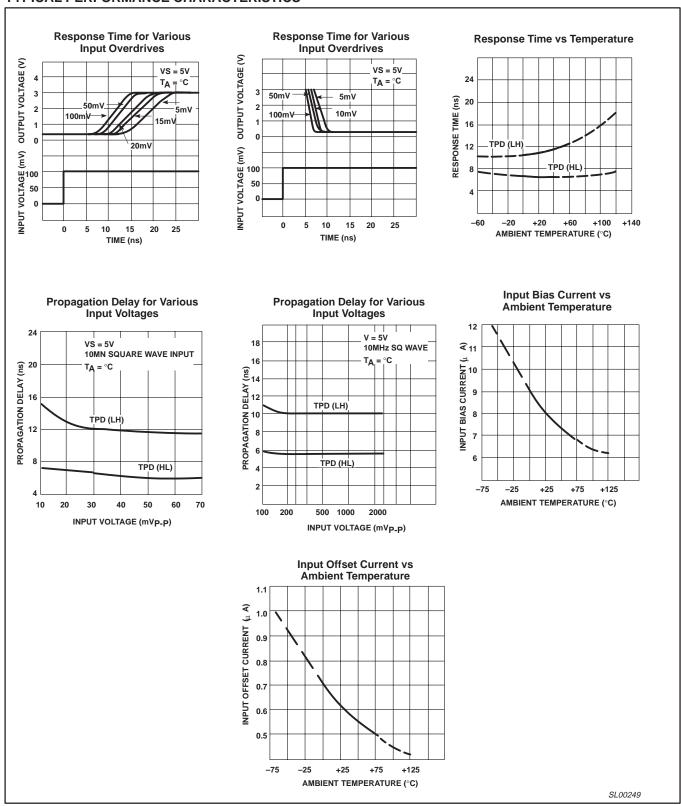


Figure 4. Typical Performance Characteristics

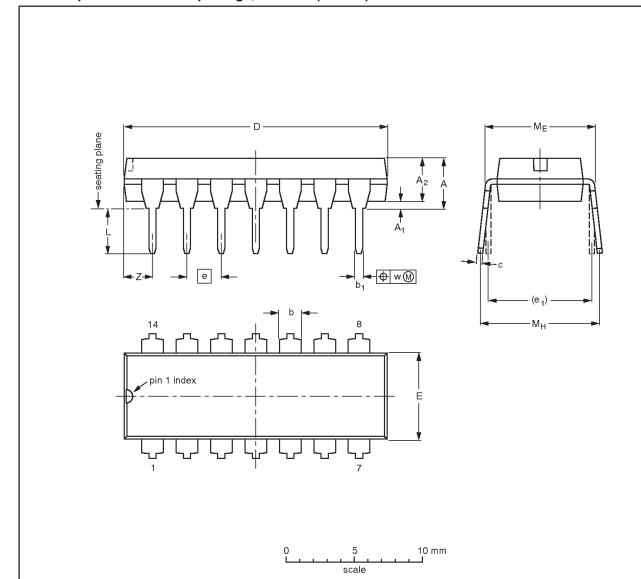
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DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	Мн	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFEF	EUROPEAN	ISSUE DATE			
VERSION	IEC JEDEC		EIAJ		PROJECTION	ISSUE DATE	
SOT27-1	050G04	MO-001	SC-501-14			95-03-11 99-12-27	

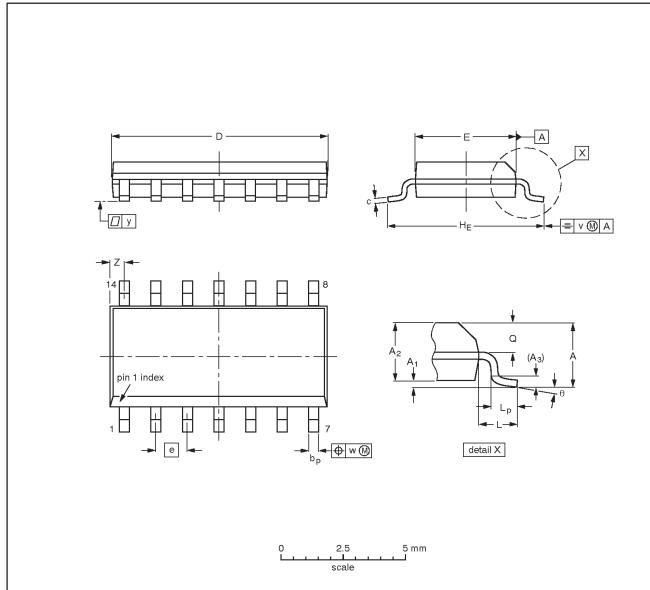
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SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	А3	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	>	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01	0.019 0.014	0.0100 0.0075	0.35 0.34	0.16 0.15	0.050	0.244 0.228	0.041	0.039 0.016		0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN ISSUE DATE					
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE			
SOT108-1	076E06	MS-012				-97-05-22 99-12-27			

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NOTES

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Data sheet status

Data sheet status ^[1]	Product status ^[2]	Definitions
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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